

Docket No.: P2002,0635

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant : DIRK FUHRMANN ET AL.
Filed : CONCURRENTLY HEREWITH
Title : SEMICONDUCTOR MEMORY HAVING A CONFIGURATION OF
MEMORY CELLS

INFORMATION DISCLOSURE STATEMENT

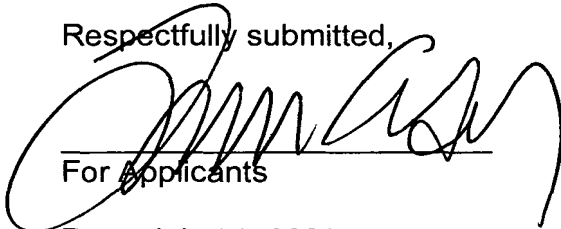
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Sir:

In accordance with 37 C.F.R. 1.98 copies of the following patents and/or publications are submitted herewith:

U.S. Patent No. 6,448,600 B1 (Schlösser et al.), dated September 10, 2002, and corresponding German Patent DE 199 54 867 C1 (Schlösser et al.), dated December 7, 2000.

Respectfully submitted,



For Applicants

LAURENCE A. GREENBERG
REG. NO. 29,308

Date: July 31, 2003

Lerner and Greenberg, P.A.
Post Office Box 2480
Hollywood, FL 33022-2480
Tel: (954) 925-1100
Fax: (954) 925-1101

/nt/kf

FORM PTO-1449 (SUBSTITUTE) U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE INFORMATION DISCLOSURE STATEMENT BY APPLICANT (37 CFR 1.98(b))				Attorney Docket No.: P2002,0635 Appl. No.: <hr/> Applicant: DIRK FUHRMANN ET AL. <hr/> Filing Date: July 31, 2003 Group Art Unit:			
EXAMINER INITIALS		PATENT NO.	DATE	PATENTEE	CLASS	SUB CLASS	FILING DATE
	A	6,448,600 B1	9/10/02	Schlösser et al.			
	B						
	C						
	D						
	E						
	F						
	G						
	H						
	I						
FOREIGN PATENT DOCUMENT							
		DOCUMENT NO.	DATE	COUNTRY	CLASS	SUB CLASS	TRANSL. YES NO
	J	199 54 867 C1	12/7/00	Germany			
	K						
	L						
	M						
	N						
OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, etc.)							
EXAMINER				DATE CONSIDERED			